



ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT				
Reverse voltage		V _R	6.0	V
DC forward current		I _F	60	mA
Surge forward current	t _p ≤ 10 μs	I _{FSM}	2.5	A
Total power dissipation		P _{diss}	100	mW
OUTPUT				
Collector emitter voltage		V _{CEO}	70	V
Emitter base voltage		V _{EB}	7.0	V
Collector current		I _C	50	mA
	t = 1.0 ms	I _C	100	mA
Power dissipation		P _{diss}	150	mW
COUPLER				
Storage temperature range		T _{stg}	-55 to +150	°C
Ambient temperature range		T _{amb}	-55 to +100	°C
Junction temperature	Max. 10 s, dip soldering	T _j	100	°C
Soldering temperature ⁽¹⁾	Max. 10 s, dip soldering: distance to seating plane ≥ 1.5 mm	T _{sld}	260	°C

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability
- ⁽¹⁾ Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP)

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT							
Forward voltage	I _F = 60 mA		V _F	-	1.25	1.65	V
Breakdown voltage	I _R = 10 μA		V _{BR}	6	-	-	V
Reverse current	V _R = 6 V		I _R	-	0.01	10	μA
Capacitance	V _F = 0 V, f = 1 MHz		C _O	-	25	-	pF
Thermal resistance			R _{thja}	-	750	-	K/W
OUTPUT							
Collector emitter capacitance	f = 1 MHz, V _{CE} = 5 V		C _{CE}	-	5.2	-	pF
Collector base capacitance	f = 1 MHz, V _{CB} = 5 V		C _{CB}	-	6.5	-	pF
Emitter base capacitance	f = 1 MHz, V _{EB} = 5 V		C _{EB}	-	9.5	-	pF
Thermal resistance			R _{thja}	-	500	-	K/W
Collector emitter leakage current	V _{CE} = 10 V	SFH600-1	I _{CEO}	-	2	35	nA
		SFH600-2	I _{CEO}	-	2	35	nA
		SFH600-3	I _{CEO}	-	5	70	nA
COUPLER							
Saturation voltage collector emitter voltage	I _F = 10 mA, I _C = 2.5 mA		V _{CEsat}	-	0.25	0.4	V
Capacitance (input to output)			C _{IO}	-	-	0.6	pF

Note

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements



CURRENT TRANSFER RATIO							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
I_C/I_F at $V_{CE} = 5.0\text{ V}$	$I_F = 10\text{ mA}$	SFH600-1	CTR	63	-	125	%
		SFH600-2	CTR	100	-	200	%
		SFH600-3	CTR	160	-	320	%
	$I_F = 1\text{ mA}$	SFH600-1	CTR	22	45	-	%
		SFH600-2	CTR	34	70	-	%
		SFH600-3	CTR	56	90	-	%

SWITCHING CHARACTERISTICS							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
NON-SATURATED							
Current	$V_{CC} = 5\text{ V}, R_L = 75\ \Omega$		I_F	-	10	-	mA
Rise time	$V_{CC} = 5\text{ V}, R_L = 75\ \Omega$		t_r	-	2	-	μs
Fall time	$V_{CC} = 5\text{ V}, R_L = 75\ \Omega$		t_f	-	2.5	-	μs
Turn-on time	$V_{CC} = 5\text{ V}, R_L = 75\ \Omega$		t_{on}	-	3.2	-	μs
Turn-off time	$V_{CC} = 5\text{ V}, R_L = 75\ \Omega$		t_{off}	-	3	-	μs
Cut-off frequency	$V_{CC} = 5\text{ V}, R_L = 75\ \Omega$		F_{CO}	-	250	-	kHz
SATURATED							
Current		SFH600-1	I_F	-	10	-	mA
		SFH600-2	I_F	-	10	-	mA
		SFH600-3	I_F	-	5	-	mA
Rise time		SFH600-1	t_r	-	3	-	μs
		SFH600-2	t_r	-	3	-	μs
		SFH600-3	t_r	-	4	-	μs
Fall time		SFH600-1	t_f	-	12	-	μs
		SFH600-2	t_f	-	12	-	μs
		SFH600-3	t_f	-	14	-	μs
Turn-on time		SFH600-1	t_{on}	-	4.5	-	μs
		SFH600-2	t_{on}	-	4.5	-	μs
		SFH600-3	t_{on}	-	5.8	-	μs
Turn-off time		SFH600-1	t_{off}	-	21	-	μs
		SFH600-2	t_{off}	-	21	-	μs
		SFH600-3	t_{off}	-	24	-	μs

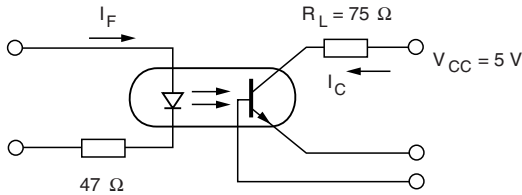
SAFETY AND INSULATION RATINGS				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Climatic classification	According to IEC 68 part 1		55 / 100 / 21	
Comparative tracking index		CTI	175	
Maximum rated withstanding isolation voltage	$t = 1\text{ min}$	V_{ISO}	4420	V_{RMS}
Maximum transient isolation voltage		V_{IOTM}	10 000	V
Maximum repetitive peak isolation voltage		V_{IORM}	890	V
Isolation resistance	$V_{IO} = 500\text{ V}, T_{amb} = 25\text{ }^\circ\text{C}$	R_{IO}	$\geq 10^{12}$	Ω
	$V_{IO} = 500\text{ V}, T_{amb} = 100\text{ }^\circ\text{C}$	R_{IO}	$\geq 10^{11}$	Ω
Output safety power		P_{SO}	400	mW
Input safety current		I_{SI}	275	mA
Input safety temperature		T_{SI}	175	$^\circ\text{C}$
Creepage distance			≥ 7	mm
Clearance distance			≥ 7	mm
Insulation thickness		DTI	≥ 0.4	mm

Note

- As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits

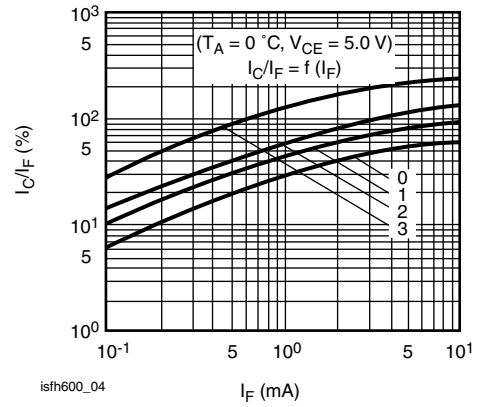


TYPICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)



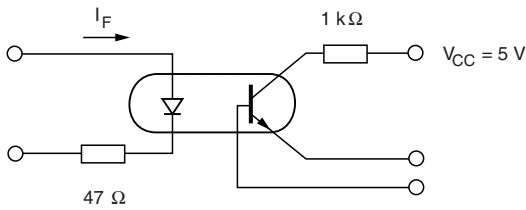
isfh600_01

Fig. 1 - Linear Operation (without saturation)



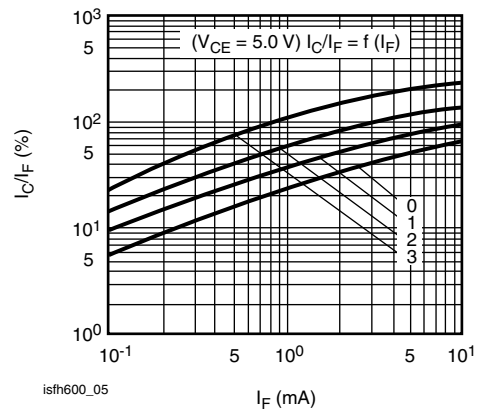
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Fig. 4 - Current Transfer Ratio vs. Diode Current



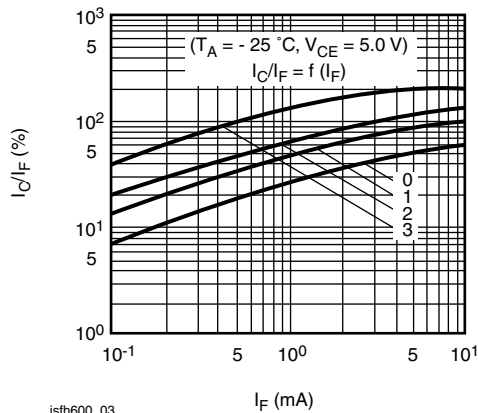
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Fig. 2 - Switching Operation (with saturation)



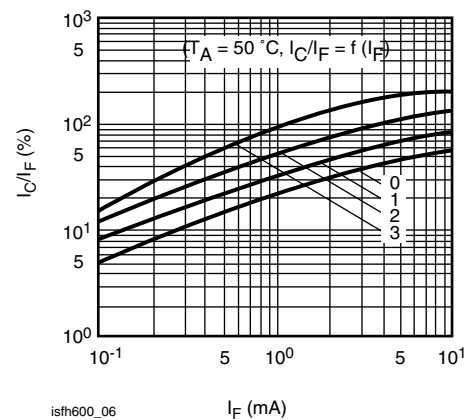
isfh600_05

Fig. 5 - Current Transfer Ratio vs. Diode Current



isfh600_03

Fig. 3 - Current Transfer Ratio vs. Diode Current



isfh600_06

Fig. 6 - Current Transfer Ratio vs. Diode Current

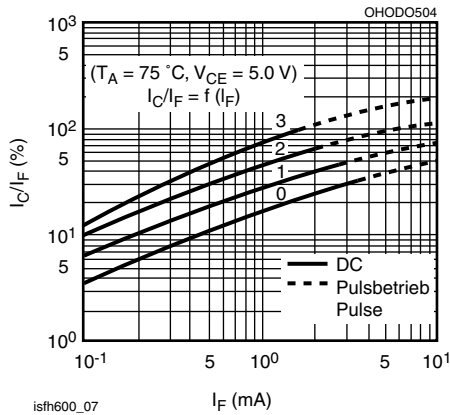


Fig. 7 - Current Transfer Ratio vs. Diode Current

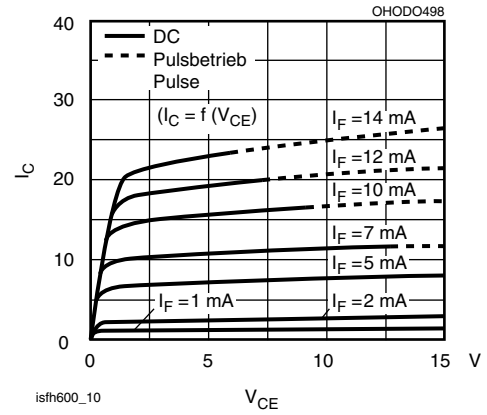


Fig. 10 - Output Characteristics SFH600-2, SFH600-3

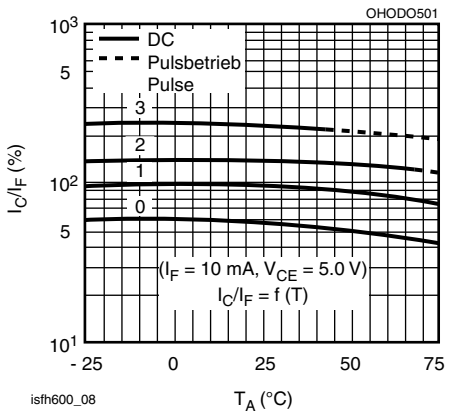


Fig. 8 - Current Transfer Ratio (CTR) vs. Temperature

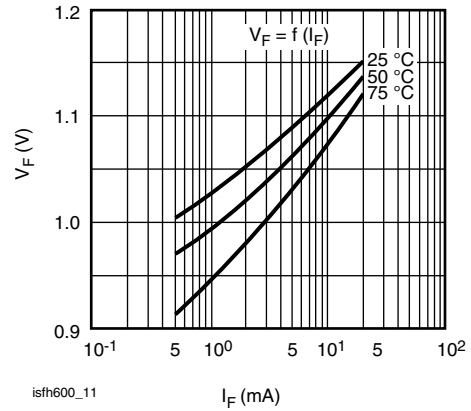


Fig. 11 - Forward Voltage

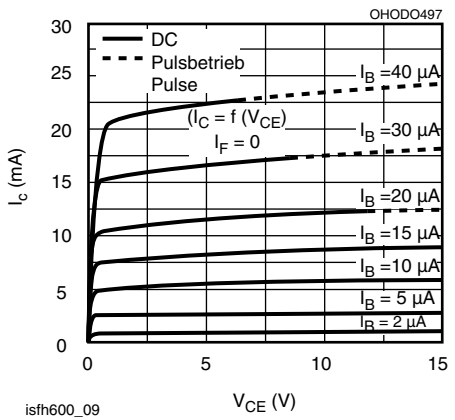


Fig. 9 - Transistor Characteristics SFH600-2, SFH600-3

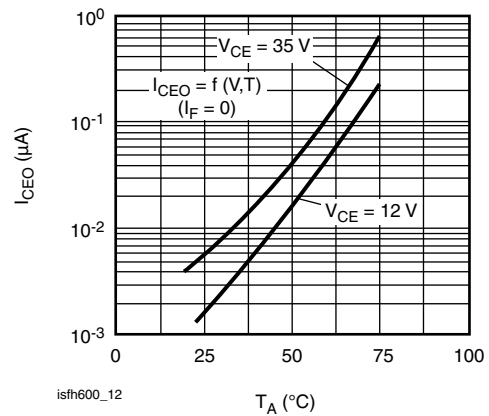


Fig. 12 - Collector Emitter Off-State Current

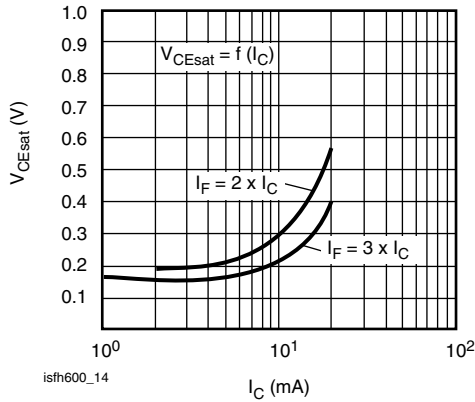


Fig. 13 - Saturation Voltage vs. Collector Current and Modulation Depth SFH600-1

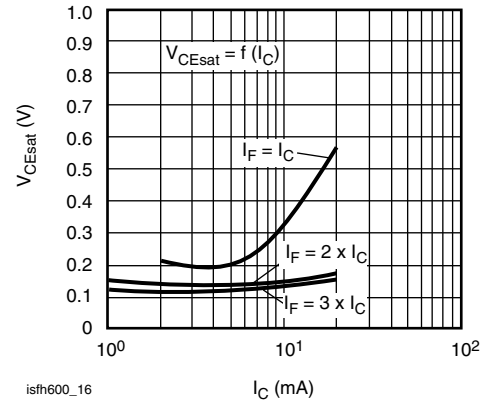


Fig. 16 - Permissible Pulse Load

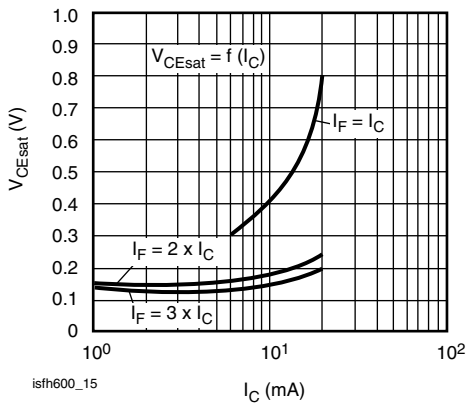


Fig. 14 - Saturation Voltage vs. Collector Current and Modulation Depth SFH600-2

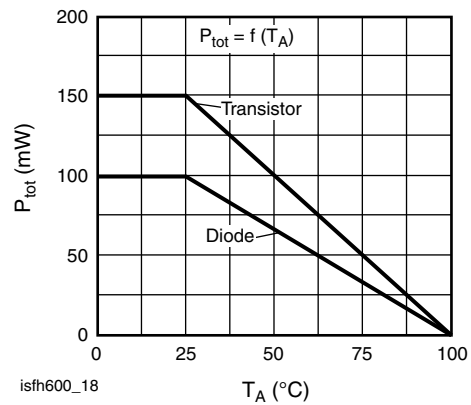


Fig. 17 - Permissible Power Dissipation for Transistor and Diode

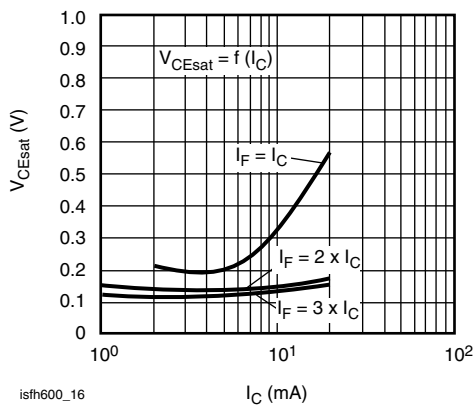


Fig. 15 - Saturation Voltage vs. Collector Current and Modulation Depth SFH600-3

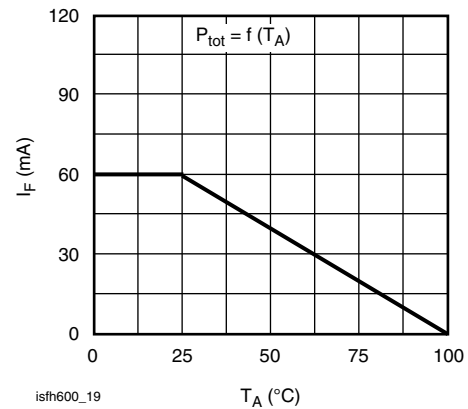
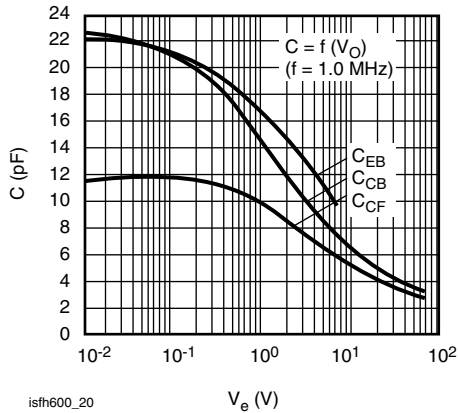


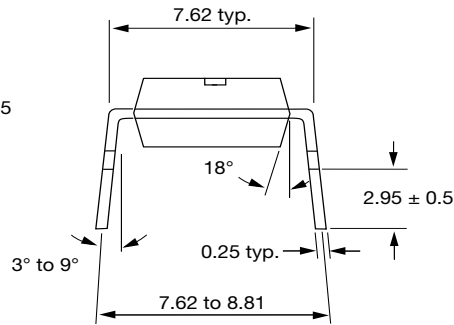
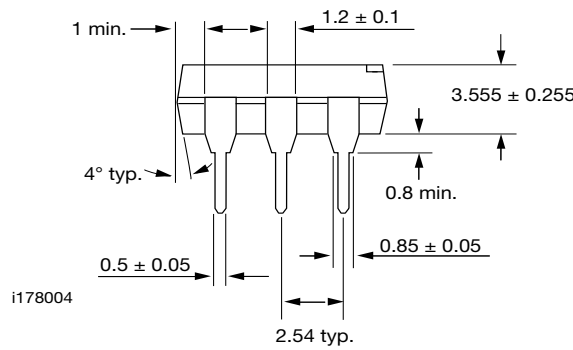
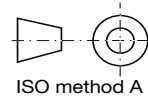
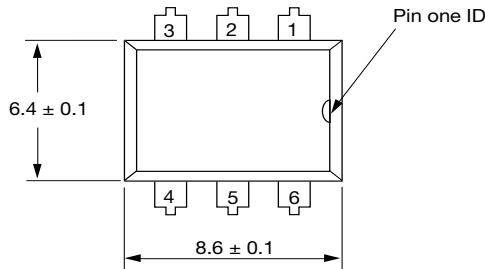
Fig. 18 - Permissible Forward Current Diode



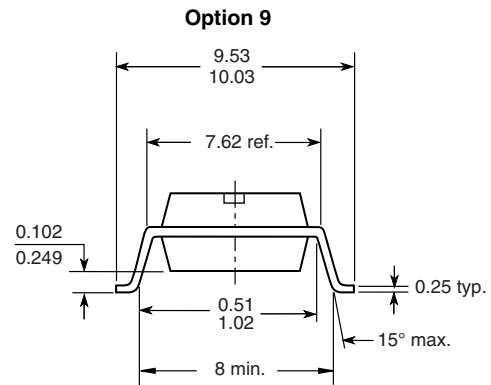
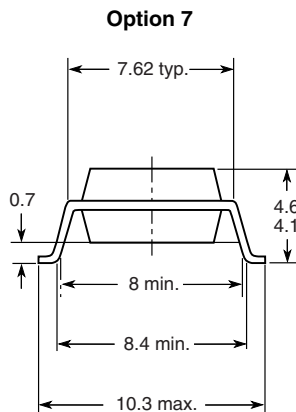
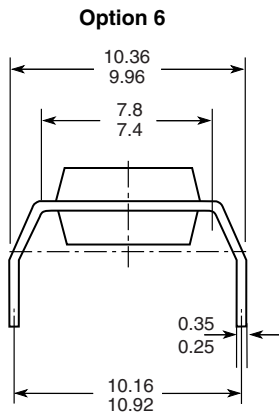
isfh600_20

Fig. 19 - Transistor Capacitance

PACKAGE DIMENSIONS in inches (millimeters)



i178004



18450



PACKAGE MARKING (example)

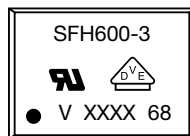


Fig. 20 - Example of SFH600-3X001

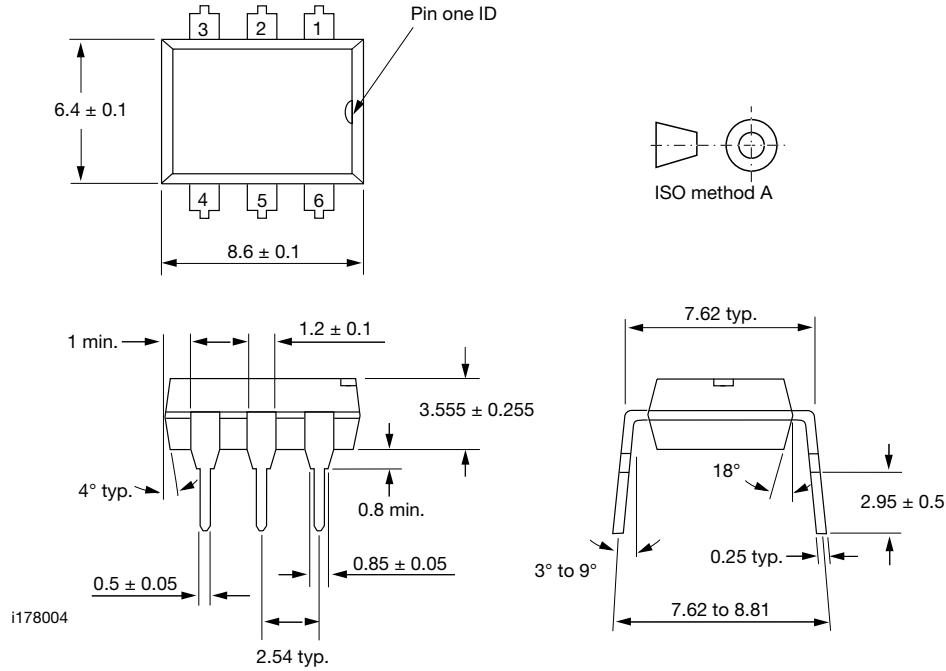
Notes

- XXXX = LMC (lot marking code)
- VDE logo is only marked on option 1 parts
- Tape and reel suffix (T) is not part of the package marking



DIP-6A

PACKAGE DIMENSIONS in inches (millimeters)



Note

The information in this document provides generic information but for specific information on a product the appropriate product datasheet should be used.



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